Power Semiconductor Devices General Engineering By B

For junior or senior undergraduate students in Electrical and Electronic Engineering. This text is also suitable for individuals interested in the fields of electrical and electronic engineering. This text covers the basics of emerging areas in power electronics and a broad range of topics such as power switching devices, conversion methods, analysis and techniques, and applications. Its unique approach covers the characteristics of semiconductor devices first, then discusses the applications of these devices for power conversions. Four main applications are included: flexible ac transmissions (FACTs), static switches, power supplies, dc drives, and ac drives.

This publication discusses general problems related to the structure of current overload protection systems in high voltage (HV) electrical installations and introduces a family of new devices based on reed switch contacts, solid-state units, hybrid technology and automatic systems based on these components. It highlights their application in high

During the last decade, many new concepts have been proposed for improving the performance of power rectifiers and transistors. The results of this research are dispersed in the technical literature among journal articles and abstracts of conferences. Consequently, the information is not readily available to researchers and practicing engineers in the power device community. There is no cohesive treatment of the ideas to provide an assessment of the relative merits of the ideas. Advanced Power Rectifier Concepts provides an in-depth treatment of the physics of operation of advanced power rectifiers. Analytical models for explaining the operation of all the advanced power rectifier devices will be developed. The results of numerical simulations will be provided to provide additional insight into the device physics and validate the analytical models. The results of two-dimensional simulations will be provided to corroborate the analytical models and provide greater insight into the device operation.

Semiconductor power devices are the heart of power electronics. They determine the performance of power converters and allow topologies with high efficiency. Semiconductor properties, pn-junctions and the physical phenomena for understanding power devices are discussed in depth. Working principles of state-of-the-art power diodes, thyristors, MOSFETs and IGBTs are explained in detail, as well as key aspects of semiconductor device production technology. In practice, not only the semiconductor, but also the thermal and mechanical properties of packaging and interconnection technologies are essential to predict device behavior in circuits. Wear and aging mechanisms are identified and reliability analyses principles are developed. Unique information on destructive mechanisms, including typical failure pictures, allows assessment of the ruggedness of power devices. Also parasitic effects, such as device induced electromagnetic interference problems, are addressed. The
This reference book provides a fully integrated novel approach to the development of high-power, single-transverse mode, edge-emitting diode lasers by addressing the complementary topics of device engineering, reliability engineering and device diagnostics in the same book, and thus closes the gap in the current book literature. Diode laser fundamentals are discussed, followed by an elaborate discussion of problem-oriented design guidelines and techniques, and by a systematic treatment of the origins of laser degradation and a thorough exploration of the engineering means to enhance the optical strength of the laser. Stability criteria of critical laser characteristics and key laser robustness factors are discussed along with clear design considerations in the context of reliability engineering approaches and models, and typical programs for reliability tests and laser product qualifications. Novel, advanced diagnostic methods are reviewed to discuss, for the first time in detail in book literature, performance- and reliability-impacting factors such as temperature, stress and material instabilities. Further key features include: practical design guidelines that consider also reliability related effects, key laser robustness factors, basic laser fabrication and packaging issues; detailed discussion of diagnostic investigations of diode lasers, the fundamentals of the applied approaches and techniques, many of them pioneered by the author to be fit-for-purpose and novel in the application; systematic insight into laser degradation modes such as catastrophic optical damage, and a wide range of technologies to increase the optical strength of diode lasers; coverage of basic concepts and techniques of laser reliability engineering with details on a standard commercial high power laser reliability test program. Semiconductor Laser Engineering, Reliability and Diagnostics reflects the extensive expertise of the author in the diode laser field both as a top scientific researcher as well as a key developer of high-power highly reliable devices. With invaluable practical advice, this new reference book is suited to practising researchers in diode laser technologies, and to postgraduate engineering students. Dr. Peter W. Epperlein is Technology Consultant with his own semiconductor technology consulting business Pwe-PhotonicsElectronics-IssueResolution in the UK. He looks back at a thirty years career in cutting edge photonics and electronics industries with focus on emerging technologies, both in global and start-up companies, including IBM, Hewlett-Packard, Agilent Technologies, Philips/NXP, Essient Photonics and IBM/JDSU Laser Enterprise. He holds Pre-Dipl. (B.Sc.), Dipl. Phys. (M.Sc.) and Dr. rer. nat.
(Ph.D.) degrees in physics, magna cum laude, from the University of Stuttgart, Germany. Dr. Epperlein is an internationally recognized expert in compound semiconductor and diode laser technologies. He has accomplished R&D in many device areas such as semiconductor lasers, LEDs, optical modulators, quantum well devices, resonant tunneling devices, FETs, and superconducting tunnel junctions and integrated circuits. His pioneering work on sophisticated diagnostic research has led to many world’s first reports and has been adopted by other researchers in academia and industry. He authored more than seventy peer-reviewed journal papers, published more than ten invention disclosures in the IBM Technical Disclosure Bulletin, has served as reviewer of numerous proposals for publication in technical journals, and has won five IBM Research Division Awards. His key achievements include the design and fabrication of high-power, highly reliable, single mode diode lasers. Book Reviews “Semiconductor L

For ease of use, this edition has been divided into the following subject sections: general principles; materials and processes; control, power electronics and drives; environment; power generation; transmission and distribution; power systems; sectors of electricity use. New chapters and major revisions include: industrial instrumentation; digital control systems; programmable controllers; electronic power conversion; environmental control; hazardous area technology; electromagnetic compatibility; alternative energy sources; alternating current generators; electromagnetic transients; power system planning; reactive power plant and FACTS controllers; electricity economics and trading; power quality. *An essential source of techniques, data and principles for all practising electrical engineers *Written by an international team of experts from engineering companies and universities *Includes a major new section on control systems, PLCs and microprocessors

Fundamentals of Power Semiconductor Devices provides an in-depth treatment of the physics of operation of power semiconductor devices that are commonly used by the power electronics industry. Analytical models for explaining the operation of all power semiconductor devices are shown. The treatment here focuses on silicon devices but includes the unique attributes and design requirements for emerging silicon carbide devices. The book will appeal to practicing engineers in the power semiconductor device community.

This book relates the recent developments in several key electrical engineering R&D labs, concentrating on power electronics switches and their use. The first sections deal with key power electronics technologies, MOSFETs and IGBTs, including series and parallel associations. The next section examines silicon carbide and its potentiality for power electronics applications and its present limitations. Then, a dedicated section presents the capacitors, key passive components in power electronics, followed by a modeling method allowing the stray inductances computation, necessary for the precise simulation of switching waveforms. Thermal behavior associated with power switches follows, and the last part proposes some interesting perspectives associated to Power Electronics integration.
Projects in Electrical, Electronics, Instrumentation and Computer Engineering @

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The IGBT Device
Silicon Carbide Power Devices
Power Electronics and Motor Drives
Advanced Power Rectifier Concepts

Explaining the physics and characteristics of power semiconductor devices, this book presents an overview of various classes of power semiconductors. It provides insight into how they work and the characteristics of the various components from the viewpoint of the user, going through all modern power semiconductor device types. The physics are explained in reasonable detail, providing the precise amount of information needed to fully understand the component's behavior in the application. Exploring the specific strengths and weaknesses of each device type, the book demonstrates how these devices fit into the system and how they will behave there.

Power Electronics and Motor Drive Systems is designed to aid electrical engineers, researchers, and students to analyze and address common problems in state-of-the-art power electronics technologies. Author Stefanos Manias supplies a detailed discussion of the theory of power electronics circuits and electronic power conversion technology systems, with common problems and methods of analysis to critically evaluate results. These theories are reinforced by simulation examples using well-known and widely available software programs, including SPICE, PSIM, and MATLAB/SIMULINK. Manias expertly analyzes power electronic circuits with basic power semiconductor devices, as well as the new power electronic converters. He also clearly and comprehensively provides an analysis of modulation and output voltage, current control techniques, passive and active filtering, and the characteristics and gating circuits of different power semiconductor switches, such as BJTs, IGBTs, MOSFETs, IGCTs, MCTs and GTOs. Includes step-by-step analysis of power electronic systems Reinforced by simulation examples using SPICE, PSIM, and MATLAB/SIMULINK Provides 110 common problems and solutions in power electronics technologies

The 'Power Electronics Handbook' is a complete reference volume for the professional engineer. A special emphasis is placed on the actual design process of systems for sectors ranging from aerospace to domestic, transport and telecommunications. Is it possible to design and make automatic devices for industrial and power engineering without microcircuits and microprocessors and without complex power supplies? Electronic Devices on Discrete Components for Industrial and Power Engineering answers the question above with a resounding “Yes!” by describing ten original automatic devices based exclusively on modern discrete components. The book reveals that devices based on high-voltage transistors and thyristors as well as miniature vacuum and high power gas-filled reed switches are actually much simpler to implement and more reliable than traditional devices. By identifying elementary functional modules and the basic working principles of semi-conductor devices, the text allows for the construction of complete automatic devices. It also contains an extensive reference section that includes information on modern high-voltage bipolar, FET and IGBT transistors, thyristors and triacs, as well as reed switches.


Physics, Design and Applications of the Insulated Gate Bipolar Transistor
Power Semiconductors
Power Electronics and Motor Drive Systems
Semiconductor Power Devices
A concise and hands-on overview of medium voltage direct current (MVDC) technology for electric power grids, written by international experts with broad experience. The book covers fundamentals, converters, transformers and control for both stationary and mobile applications.


Power electronics, which is a rapidly growing area in terms of research and applications, uses modern electronics technology to convert electric power from one form to another, such as ac-dc, dc-dc, dc-ac, and ac-ac with a variable output magnitude and frequency. Power electronics has many applications in our everyday life such as air-conditioners, electric cars, subway trains, motor drives, renewable energy sources and power supplies for computers. This book covers all aspects of switching devices, converter circuit topologies, control techniques, analytical methods and some examples of their applications. * 25% new content * Reorganized and revised into 8 sections comprising 43 chapters * Coverage of numerous applications, including uninterruptable power supplies and automotive electrical systems * New content in power generation and distribution, including solar power, fuel cells, wind turbines, and flexible transmission

Designed for polytechnic and undergraduate students of electrical/electronics, this book offers short questions and answers at the end of chapters. It is also suitable for those preparing for professional courses like AMIE and AMITE.

Wide Bandgap Semiconductor Power Devices
Advanced Power Electronics Converters
Low Power Semiconductor Devices and Processes for Emerging Applications in Communications, Computing, and Sensing
Characterization of Wide Bandgap Power Semiconductor Devices
Physics, Characteristics, Reliability

This book covers power electronics, in depth, by presenting the basic principles and application details, which can be used both as a textbook and reference book. Introduces a new method to present power electronics converters called Power Blocks Geometry (PBG) Applicable for courses focusing on power electronics, power electronics
converters, and advanced power converters. Offers a comprehensive set of simulation results to help understand the circuits presented throughout the book.

"Discusses the essential concepts of power electronics through MATLAB examples and simulations"--

During the last decade, many new concepts have been proposed for improving the performance of power MOSFETs. The results of this research are dispersed in the technical literature among journal articles and abstracts of conferences. Consequently, the information is not readily available to researchers and practicing engineers in the power device community. There is no cohesive treatment of the ideas to provide an assessment of the relative merits of the ideas. "Advanced Power MOSFET Concepts" provides an in-depth treatment of the physics of operation of advanced power MOSFETs. Analytical models for explaining the operation of all the advanced power MOSFETs will be developed. The results of numerical simulations will be provided to give additional insight into the device physics and validate the analytical models. The results of two-dimensional simulations will be provided to corroborate the analytical models and give greater insight into the device operation.

To be accredited, a power electronics course should cover a significant amount of design content and include extensive use of computer-aided analysis with simulation tools such as SPICE. Based upon the authors' experience in designing such courses, SPICE for Power Electronics and Electric Power, Second Edition integrates a SPICE simulator with a...
frequency ranges. The many tables presented in the book provide an easily used reference source.

The IGBT device has proved to be a highly important Power Semiconductor, providing the basis for adjustable speed motor drives (used in air conditioning and refrigeration and railway locomotives), electronic ignition systems for gasoline-powered motor vehicles and energy-saving compact fluorescent light bulbs. Recent applications include plasma displays (flat-screen TVs) and electric power transmission systems, alternative energy systems and energy storage. This book is the first available to cover the applications of the IGBT, and provide the essential information needed by applications engineers to design new products using the device, in sectors including consumer, industrial, lighting, transportation, medical and renewable energy. The author, B. Jayant Baliga, invented the IGBT in 1980 while working for GE. His book will unlock IGBT for a new generation of engineering applications, making it essential reading for a wide audience of electrical engineers and design engineers, as well as an important publication for semiconductor specialists. Essential design information for applications engineers utilizing IGBTs in the consumer, industrial, lighting, transportation, medical and renewable energy sectors. Readers will learn the methodology for the design of IGBT chips including edge terminations, cell topologies, gate layouts, and integrated current sensors. The first book to cover applications of the IGBT, a device manufactured around the world by more than a dozen companies with sales exceeding $5 Billion; written by the inventor of the device.

A comprehensive guide to full-time degree courses, institutions and towns in Britain. This book covers the fundamentals and significance of 2-D materials and related semiconductor transistor technologies for the next-generation ultra low power applications. It provides comprehensive coverage on advanced low power transistors such as NCFETs, FinFETs, TFETs, and flexible transistors for future ultra low power applications owing to their better subthreshold swing and scalability. In addition, the text examines the use of field-effect transistors for biosensing applications and covers design considerations and compact modeling of advanced low power transistors such as NCFETs, FinFETs, and TFETs. TCAD simulation examples are also provided. FEATURES Discusses the latest updates in the field of ultra low power semiconductor transistors Provides both experimental and analytical solutions for TFETs and NCFETs Presents synthesis and fabrication processes for FinFETs Reviews details on 2-D materials and 2-D transistors Explores the application of FETs for biosensing in the healthcare field This book is aimed at researchers, professionals, and graduate students in electrical engineering, electronics and communication engineering, electron devices, nanoelectronics and nanotechnology, microelectronics, and solid-state circuits.

Electronic Devices on Discrete Components for Industrial and Power Engineering

Power Semiconductor Devices

Fundamentals of Power Semiconductor Devices

Devices, Circuits, and Applications

Medium Voltage DC System Architectures

*The Industrial Electronics Handbook, Second Edition* combines traditional and newer, more specialized knowledge that will help industrial electronics engineers develop practical solutions for the design and implementation of high-power applications. Embracing the broad technological scope of the field, this collection explores fundamental areas, including analog and digital circuits, electronics, electromagnetic machines, signal processing, and industrial control and communications systems. It also facilitates the use of intelligent systems—such as neural
networks, fuzzy systems, and evolutionary methods—in terms of a hierarchical structure that makes factory control and supervision more efficient by addressing the needs of all production components. Enhancing its value, this fully updated collection presents research and global trends as published in the IEEE Transactions on Industrial Electronics Journal, one of the largest and most respected publications in the field. Power Electronics and Motor Drives facilitates a necessary shift from low-power electronics to the high-power varieties used to control electromechanical systems and other industrial applications. This volume of the handbook: Focuses on special high-power semiconductor devices Describes various electrical machines and motors, their principles of operation, and their limitations Covers power conversion and the high-efficiency devices that perform the necessary switchover between AC and DC Explores very specialized electronic circuits for the efficient control of electric motors Details other applications of power electronics, aside from electric motors—including lighting, renewable energy conversion, and automotive electronics Addresses power electronics used in very-high-power electrical systems to transmit energy Other volumes in the set: Fundamentals of Industrial Electronics Control and Mechatronics Industrial Communication Systems Intelligent Systems

This book includes my lecture notes for power electronics course. The characteristics and operation of electronic power devices, firing circuits, and driving circuits for power converters are described and implemented practically in the laboratory. Uncontrolled and controlled, single phase rectifiers are used in various electrical power applications. DC to DC power conversion circuits are investigated. Circuit simulation and practical laboratories are utilized to reinforce concepts. The book is divided into different learning parts: · Part 1: Describe the characteristics and operation of electronic power devices. · Part 2: Describe firing and driving circuits for power electronic converters. · Part 3: Analyze the use of uncontrolled and controlled single-phase rectifiers in various electrical power applications. · Part 4: Investigate the DC-to-DC power conversion circuits used in power applications.

Part 1: Describe the characteristics and operation of electronic power devices.

1. Describe diode characteristics, types (power diode, general-purpose, and fast recovery), and connections (series, parallel and freewheeling).
2. Describe thyristor characteristics, two-transistor model, and purpose of di/dt and dv/dt protection.
3. Describe the power MOSFET and IGBT characteristics.
4. Compare electronic power devices in terms of various power converter applications, frequency of operation (switching speed), rating, and switching power losses.

Part 2: Describe firing and driving circuits for power electronic converters.

1. Describe ideal and non-ideal properties of operational amplifiers. Determine the operation of various related circuits (inverting and non-inverting amplifiers, buffer amplifier, summing amplifier).
2. Describe the use of an operational amplifier for PWM generation, for triangular and sine wave generation, as a comparator, and its integration into a 555 timer.
3. Explore other basic firing and driving circuits by focusing on requirements and control features such as based on specific power devices and operational amplifier.

Part 3: Analyse the use of uncontrolled and controlled single-phase rectifiers in various
electrical power applications. 1. Determine the performance characteristics of uncontrolled single-phase, half-wave and full-wave rectifiers, with resistive and inductive loads. 2. Determine the performance characteristics of controlled single-phase, half-wave and full-wave rectifiers with resistive and inductive loads. 3. Determine the change in power factor when using uncontrolled and controlled rectifiers. Define input distortion and displacement factor. 4. Describe how power inversion may be achieved by varying the firing angle in controlled rectifiers. Part 4: Investigate the DC-to-DC power conversion circuits used in power applications. 1. State the principle of step-down and step-up operations. 2. Explain the DC chopper classification and describe switch-mode regulators. 3. Explain the operation of buck, boost. 4. Explain the operation buck-boost regulators.

The book addresses the need to investigate new approaches to lower energy requirement in multiple application areas and serves as a guide into emerging circuit technologies. It explores revolutionary device concepts, sensors, and associated circuits and architectures that will greatly extend the practical engineering limits of energy-efficient computation. The book responds to the need to develop disruptive new system architectures and semiconductor processes aimed at achieving the highest level of computational energy efficiency for general purpose computing systems. Discusses unique technologies and material only available in specialized journal and conferences. Covers emerging materials and device structures, such as ultra-low power technologies, nanoelectronics, and microsystem manufacturing. Explores semiconductor processing and manufacturing, device design, and performance. Contains practical applications in the engineering field, as well as graduate studies. Written by international experts from both academia and industry.

Wide Bandgap Semiconductor Power Devices: Materials, Physics, Design and Applications provides readers with a single resource on why these devices are superior to existing silicon devices. The book lays the groundwork for an understanding of an array of applications and anticipated benefits in energy savings. Authored by the Founder of the Power Semiconductor Research Center at North Carolina State University (and creator of the IGBT device), Dr. B. Jayant Baliga is one of the highest regarded experts in the field. He thus leads this team who comprehensively review the materials, device physics, design considerations and relevant applications discussed. Comprehensively covers power electronic devices, including materials (both gallium nitride and silicon carbide), physics, design considerations, and the most promising applications. Addresses the key challenges towards the realization of wide bandgap power electronic devices, including materials defects, performance and reliability. Provides the benefits of wide bandgap semiconductors, including opportunities for cost reduction and social impact.

A Practical Approach to High Power and Single Mode Devices Physics, Applications, and Reliability
Power Electronics with MATLAB
Semiconductor Laser Engineering, Reliability and Diagnostics
Power Electronics Semiconductor Devices

Entrepreneurship in Power Semiconductor Devices, Power Electronics, and Electric Machines and Drive Systems introduces the basics of entrepreneurship and a methodology for the study of entrepreneurship in electrical engineering and other engineering fields. Entrepreneurship is considered here in three fields of electrical engineering, viz. power semiconductor devices, power electronics and electric machines and drive systems, and their current practice. It prepares the reader by providing a review of the subject matter in the three fields, their current status in research and development with analysis aspect as needed, thus allowing readers to gain self-sufficiency while reading the book. Each field’s emerging applications, current market and future market forecasts are introduced to understand the basis and need for emerging startups. Practical learning is introduced in: (i) power semiconductor devices entrepreneurship through the prism of 20 startups in detail, (ii) power electronics entrepreneurship through 28 startup companies arranged under various application fields and (iii) electric machines and drive systems entrepreneurship through 15 startups in electromagnetic and 1 in electrostatic machines and drive systems. The book: (i) demystifies entrepreneurship in a practical way to equip engineers and students with entrepreneurship as an option for their professional growth, pursuit and success; (ii) provides engineering managers and corporate-level executives a detailed view of entrepreneurship activities in the considered three fields that may potentially impact their businesses, (iii) provides entrepreneurship education in an electrical engineering environment and with direct connection and correlation to their fields of study and (iv) endows a methodology that can be effectively employed not only in the three illustrated fields of electrical engineering but in other fields as well. This book is for electrical engineering students and professionals. For use in undergraduate and graduate courses in electrical engineering, the book contains discussion questions, exercise problems, team and class projects, all from a practical point of view, to train students and assist professionals for future entrepreneurship endeavors.

This is the eBook of the printed book and may not include any media, website access codes, or print supplements that may come packaged with the bound book. For junior or senior undergraduate students in Electrical and Electronic Engineering. This text is also suitable for individuals interested in the fields of electrical and electronic engineering. This text covers the basics of emerging areas in power electronics and a broad range of topics such as power switching devices, conversion methods, analysis and techniques, and applications. Its unique approach covers the characteristics of semiconductor devices first, then discusses the applications of these devices for power conversions. Four main applications are included: flexible ac transmissions (FACTs), static switches, power supplies, dc drives, and ac drives. At the heart of modern power electronics converters are power...
semiconductor switching devices. The emergence of wide bandgap (WBG) semiconductor devices, including silicon carbide and gallium nitride, promises power electronics converters with higher efficiency, smaller size, lighter weight, and lower cost than converters using the established silicon-based devices. However, WBG devices pose new challenges for converter design and require more careful characterization, in particular due to their fast switching speed and more stringent need for protection. Characterization of Wide Bandgap Power Semiconductor Devices presents comprehensive methods with examples for the characterization of this important class of power devices. After an introduction, the book covers pulsed static characterization; junction capacitance characterization; fundamentals of dynamic characterization; gate drive for dynamic characterization; layout design and parasitic management; protection design for double pulse test; measurement and data processing for dynamic characterization; cross-talk consideration; impact of three-phase system; and topology considerations.
Modern Power Devices

Power Electronics